SN74CBT16245C 16-BIT FET BUS SWITCH 5-V BUS SWITCH WITH –2-V UNDERSHOOT PROTECTION SCDS139 – OCTOBER 2003

 Member of the Texas Instruments	DGG, DGV, OR DL PACKAGE
Widebus™ Family	(TOP VIEW)
 Undershoot Protection for Off-Isolation on	NC 1 48 10E
A and B Ports Up to -2 V	1B1 2 47 1A1
 Bidirectional Data Flow, With Near-Zero	1B2 3 46 1 1A2
Propagation Delay	GND 4 45 GND
 Low ON-State Resistance (r_{on})	1B3 [5 44] 1A3
Characteristics (r _{on} = 3 Ω Typical)	1B4 [6 43] 1A4
 Low Input/Output Capacitance Minimizes	V _{CC} [] 7 42] V _{CC}
Loading and Signal Distortion	1B5 [] 8 41] 1A5
 (C_{io(OFF)} = 5.5 pF Typical) Data and Control Inputs Provide Undershoot Clamp Diodes 	1B6 0 9 40 1A6 GND 10 39 0 GND 1B7 0 11 38 0 1A7
 Low Power Consumption	1B8 12 37 1A8
(I _{CC} = 3 μA Max)	2B1 13 36 2A1
 V_{CC} Operating Range From 4 V to 5.5 V Data I/Os Support 0 to 5-V Signaling Levels 	2B2 [] 14 35 [] 2A2 GND [] 15 34 [] GND
(0.8-V, 1.2-V, 1.5-V, 1.8-V, 2.5-V, 3.3-V, 5-V)	2B3 [] 16 33]] 2A3 2B4 [] 17 32]] 2A4
 Control Inputs Can be Driven by TTL or	V _{CC} [18 31] V _{CC}
5-V/3.3-V CMOS Outputs	2B5 [19 30] 2A5
 I_{off} Supports Partial-Power-Down Mode	2B6 20 29 2A6
Operation	GND 21 28 GND
 Latch-Up Performance Exceeds 100 mA Per	2B7 [] 22 27 [] 2A7
JESD 78, Class II	2B8 [] 23 26 [] 2A8
ESD Performance Tested Per JESD 22	NC 24 25 20E

NC – No internal connection

Supports Both Digital and Analog
Applications: PCI Interface, Memory
Interleaving, Bus Isolation, Low-Distortion
Signal Gating

- 1000-V Charged-Device Model (C101)

description/ordering information

- 2000-V Human-Body Model

(A114-B, Class II)

TA	PACK	AGE [†]	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
–40°C to 85°C	SSOP – DL	Tube	SN74CBT16245CDL	007100450	
	550P - DL	Tape and reel	SN74CBT16245CDLR	CBT16245C	
	TSSOP – DGG Tube SN74CBT16		SN74CBT16245CDGG	CBT16245C	
	1550P - DGG	Tape and reel SN74CBT16245CDGGR		CB116245C	
	TVSOP – DGV	Tape and reel	SN74CBT16245CDGVR	CY245C	

ORDERING INFORMATION

[†]Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Widebus is a trademark of Texas Instruments.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



SN74CBT16245C 16-BIT FET BUS SWITCH 5-V BUS SWITCH WITH -2-V UNDERSHOOT PROTECTION SCDS139 - OCTOBER 2003

description/ordering information (continued)

The SN74CBT16245C is a high-speed TTL-compatible FET bus switch with low ON-state resistance (r_{on}), allowing for minimal propagation delay. Active Undershoot-Protection Circuitry on the A and B ports of the SN74CBT16245C provides protection for undershoot up to -2 V by sensing an undershoot event and ensuring that the switch remains in the proper OFF state.

The SN74CBT16245C is organized as two 8-bit bus switches with separate output-enable $(1\overline{OE}, 2\overline{OE})$ inputs. It can be used as two 8-bit bus switches or as one 16-bit bus switch. When \overline{OE} is low, the associated 8-bit bus switch is ON, and the A port is connected to the B port, allowing bidirectional data flow between ports. When \overline{OE} is high, the associated 8-bit bus switch is OFF and the high-impedance state exists between the A and B ports.

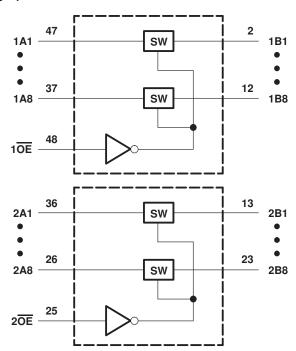
This device is fully specified for partial-power-down applications using I_{off} . The I_{off} feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

(04011 0 211 240 011101)										
INPUT OE	INPUT/OUTPUT A	FUNCTION								
L	В	A port = B port								
Н	Z	Disconnect								

FUNCTION TABLE (each 8-bit bus switch)

L



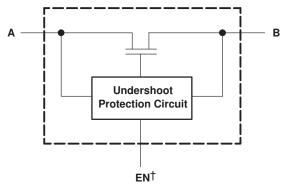
logic diagram (positive logic)



SN74CBT16245C **16-BIT FET BUS SWITCH** 5-V BUS SWITCH WITH -2-V UNDERSHOOT PROTECTION

SCDS139 - OCTOBER 2003

simplified schematic, each FET switch (SW)



[†]EN is the internal enable signal applied to the switch.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[‡]

Supply voltage range, V_{CC} Control input voltage range, V_{IN} (see Notes 1 a Switch I/O voltage range, $V_{I/O}$ (see Notes 1, 2, 3 Control input clamp current, I_{IK} ($V_{IN} < 0$) I/O port clamp current, $I_{I/OK}$ ($V_{I/O} < 0$) ON-state switch current, $I_{I/O}$ (see Note 4) Continuous current through V_{CC} or GND termin Package thermal impedance, θ_{JA} (see Note 5):	and 2) and 3) nals : DGG package DGV package	$\begin{array}{cccccccccccccccccccccccccccccccccccc$
Storage temperature range, T _{stg}	DL package	63°C/W

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltages are with respect to ground unless otherwise specified.
 - 2. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
 - 3. V_I and V_O are used to denote specific conditions for V_{I/O}.
 - 4. If and IO are used to denote specific conditions for II/O.
 - 5. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 6)

		MIN	MAX	UNIT
VCC	Supply voltage	4	5.5	V
VIH	High-level control input voltage	2	5.5	V
VIL	Low-level control input voltage	0	0.8	V
V _{I/O}	Data input/output voltage	0	5.5	V
ТА	Operating free-air temperature	-40	85	°C

NOTE 6: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



SN74CBT16245C **16-BIT FET BUS SWITCH** 5-V BUS SWITCH WITH -2-V UNDERSHOOT PROTECTION SCDS139 - OCTOBER 2003

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PA	RAMETER		TEST CONDITIC	DNS	MIN TYP†	MAX	UNIT
VIK	Control inputs	V _{CC} = 4.5 V,	I _{IN} = -18 mA			-1.8	V
V _{IKU}	Data inputs	V _{CC} = 5 V,	0 mA > I _I \ge -50 mA, V _{IN} = V _{CC} or GND,	Switch OFF		-2	V
I _{IN}	Control inputs	V _{CC} = 5.5 V,	$V_{IN} = V_{CC} \text{ or } GND$			±1	μA
IOZ‡		V _{CC} = 5.5 V,	$V_{O} = 0$ to 5.5 V, $V_{I} = 0$,	Switch OFF, V _{IN} = V _{CC} or GND		±10	μA
l _{off}		$V_{CC} = 0,$	$V_{O} = 0$ to 5.5 V,	$V_{\parallel} = 0$		10	μA
ICC		V _{CC} = 5.5 V,	$I_{I/O} = 0,$ $V_{IN} = V_{CC}$ or GND,	Switch ON or OFF		3	μA
∆ICC§	Control inputs	$V_{CC} = 5.5 V,$	One input at 3.4 V,	Other inputs at V_{CC} or GND		2.5	mA
C _{in}	Control inputs	V _{IN} = 3 V or 0			3.5		pF
Cio(OFF	=)	$V_{I/O} = 3 V \text{ or } 0,$	Switch OFF,	$V_{IN} = V_{CC}$ or GND	5.5		pF
Cio(ON))	V _{I/O} = 3 V or 0,	Switch ON,	V _{IN} = V _{CC} or GND	14		pF
		$V_{CC} = 4 V,$ TYP at $V_{CC} = 4 V$	V ₁ = 2.4 V,	I _O = -15 mA	8	12	
ron¶			V _I = 0	I _O = 64 mA	3	6	Ω
-		V _{CC} = 4.5 V		I _O = 30 mA	3		
			V _I = 2.4 V,	I _O = -15 mA	5	10	

 V_{IN} and I_{IN} refer to control inputs. V_I , V_O , I_I , and I_O refer to data pins. † All typical values are at $V_{CC} = 5 V$ (unless otherwise noted), $T_A = 25^{\circ}C$.

[‡] For I/O ports, the parameter IOZ includes the input leakage current.

§ This is the increase in supply current for each input that is at the specified voltage level, rather than V_{CC} or GND.

¶ Measured by the voltage drop between the A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER tpd [#]	FROM	TO	V _{CC} =	4 V	= V _{CC} ± 0.	UNIT	
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	
^t pd [#]	A or B	B or A		0.24		0.15	ns
ten	OE	A or B		5.4	1.5	5	ns
tdis	OE	A or B		5.6	1.5	5.6	ns

[#]The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).



SN74CBT16245C **16-BIT FET BUS SWITCH** 5-V BUS SWITCH WITH -2-V UNDERSHOOT PROTECTION

SCDS139 - OCTOBER 2003

undershoot characteristics (see Figures 1 and 2)

PARAMETER		TEST CONDI	TIONS	MIN	түр†	MAX	UNIT
VOUTU	$V_{CC} = 5.5 V,$	Switch OFF,	$V_{IN} = V_{CC} \text{ or } GND$	2	V _{OH} -0.3		V
[†] All typical values are at V _{CC} = 5 V (unl	ess otherwise no	ted), T _A = 25°C.					

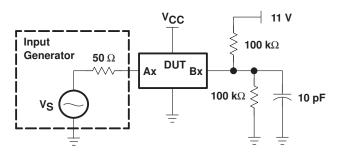


Figure 1. Device Test Setup

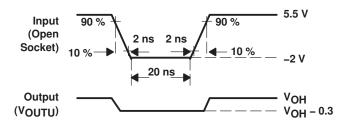
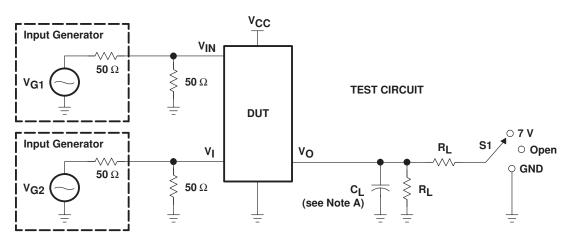


Figure 2. Transient Input Voltage (V_I) and Output Voltage (V_{OUTU}) Waveforms (Switch OFF)



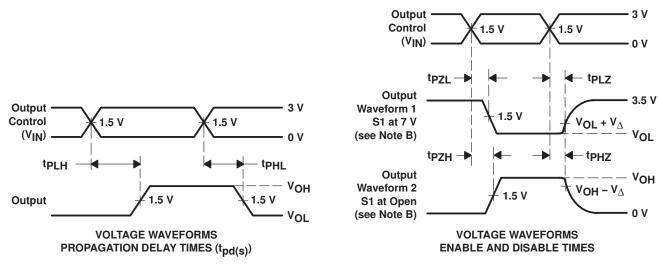
SN74CBT16245C **16-BIT FET BUS SWITCH** 5-V BUS SWITCH WITH –2-V UNDERSHOOT PROTECTION

SCDS139 - OCTOBER 2003



PARAMETER MEASUREMENT INFORMATION

TEST	VCC	S1	RL	VI	CL	v_Δ
^t pd(s)	$\begin{array}{c} 5 \text{ V} \pm 0.5 \text{ V} \\ 4 \text{ V} \end{array}$	Open Open	500 Ω 500 Ω	V _{CC} or GND V _{CC} or GND	50 pF 50 pF	
tPLZ/tPZL	$\begin{array}{c} 5 \text{ V} \pm 0.5 \text{ V} \\ 4 \text{ V} \end{array}$	7 V 7 V	500 Ω 500 Ω	GND GND	50 pF 50 pF	0.3 V 0.3 V
^t PHZ ^{/t} PZH	$\begin{array}{c} 5 \text{ V} \pm 0.5 \text{ V} \\ 4 \text{ V} \end{array}$	Open Open	500 Ω 500 Ω	V _{CC} V _{CC}	50 pF 50 pF	0.3 V 0.3 V



NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_Q = 50 Ω , t_r \leq 2.5 ns, t_f \leq 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpl 7 and tpH7 are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tPLH and tPHL are the same as tpd(s). The tpd propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
- H. All parameters and waveforms are not applicable to all devices.







PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
						.,	(6)	.,			
SN74CBT16245CDGGR	ACTIVE	TSSOP	DGG	48	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBT16245C	Samples
SN74CBT16245CDGVR	ACTIVE	TVSOP	DGV	48	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CY245C	Samples
SN74CBT16245CDL	ACTIVE	SSOP	DL	48	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBT16245C	Samples
SN74CBT16245CDLR	ACTIVE	SSOP	DL	48	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBT16245C	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and



www.ti.com

10-Dec-2020

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

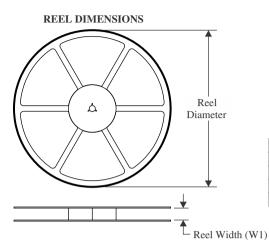
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

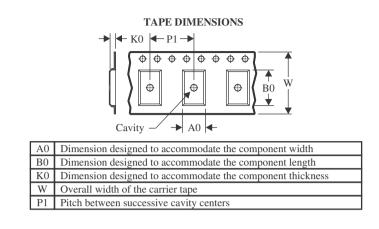


Texas

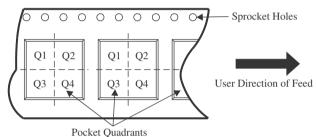
www.ti.com

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



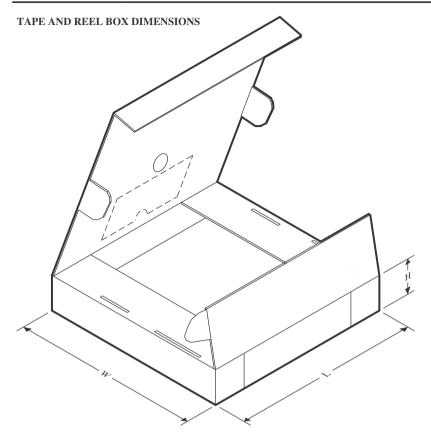
*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74CBT16245CDGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	13.0	1.8	12.0	24.0	Q1
SN74CBT16245CDGVR	TVSOP	DGV	48	2000	330.0	16.4	7.1	10.2	1.6	12.0	16.0	Q1
SN74CBT16245CDLR	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1



www.ti.com

PACKAGE MATERIALS INFORMATION

3-Jun-2022



*All dimensions are nominal

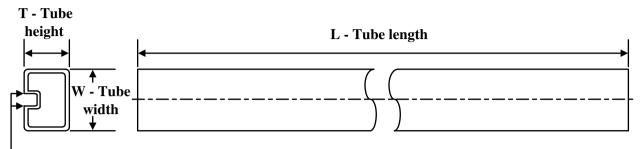
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74CBT16245CDGGR	TSSOP	DGG	48	2000	367.0	367.0	45.0
SN74CBT16245CDGVR	TVSOP	DGV	48	2000	356.0	356.0	35.0
SN74CBT16245CDLR	SSOP	DL	48	1000	367.0	367.0	55.0

TEXAS INSTRUMENTS

www.ti.com

3-Jun-2022

TUBE



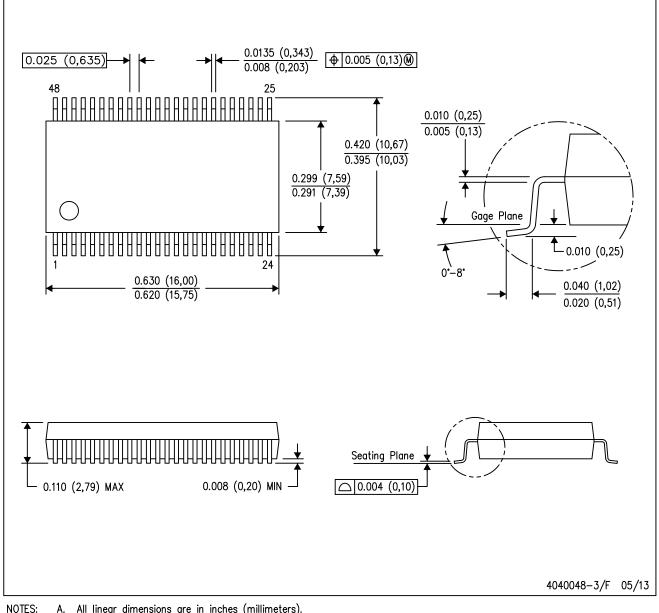
- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
SN74CBT16245CDL	DL	SSOP	48	25	473.7	14.24	5110	7.87

DL (R-PDSO-G48)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.



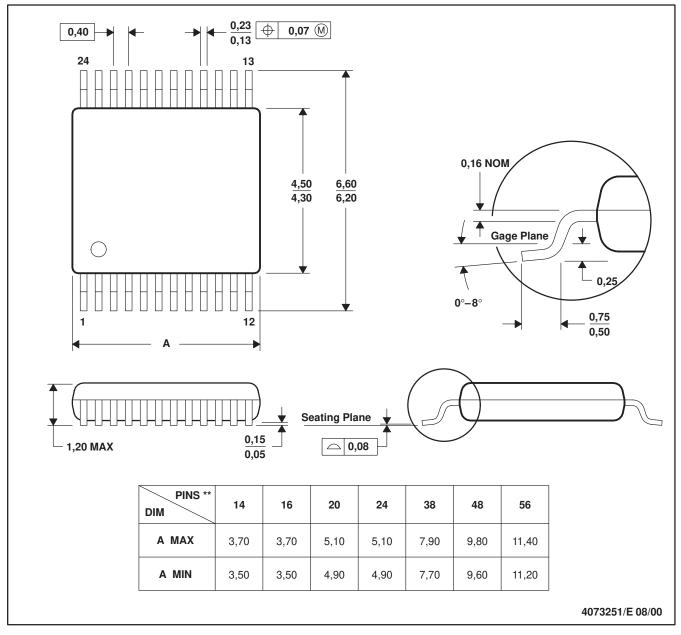
MECHANICAL DATA

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

DGV (R-PDSO-G**)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins - MO-153

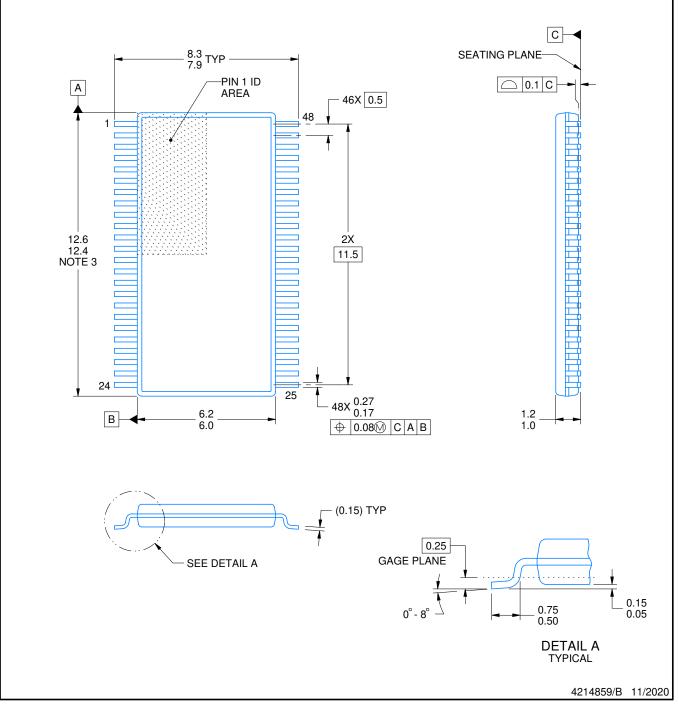
14/16/20/56 Pins – MO-194



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not

- exceed 0.15 mm per side. 4. Reference JEDEC registration MO-153.



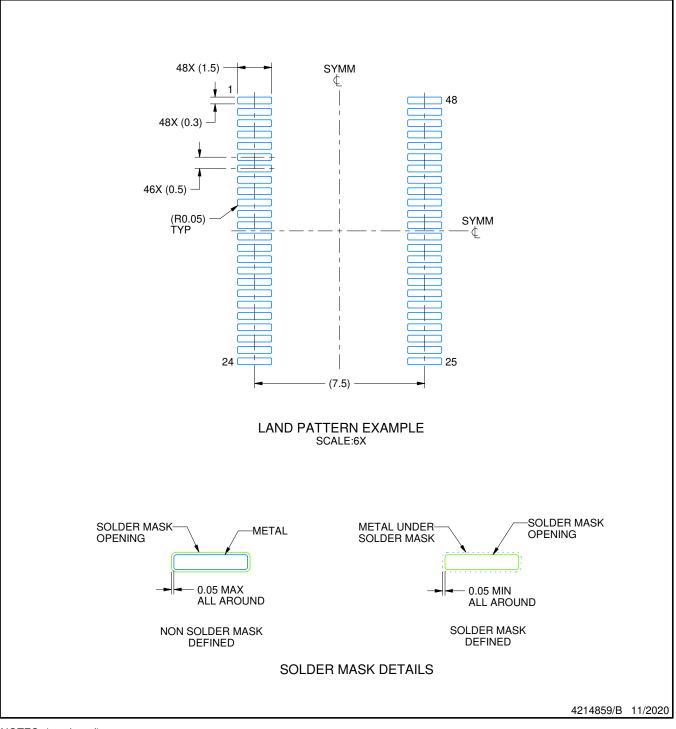
DGG0048A

DGG0048A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

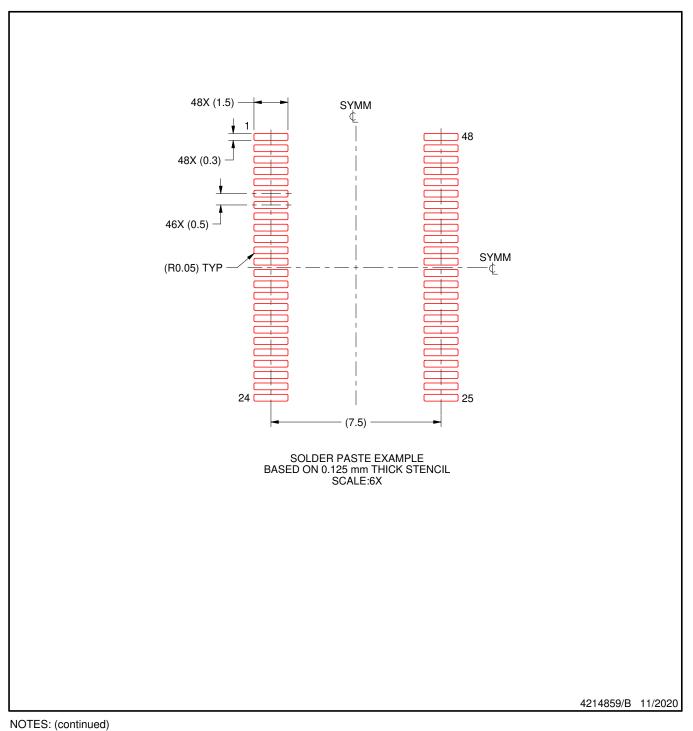


DGG0048A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

8. Board assembly site may have different recommendations for stencil design.



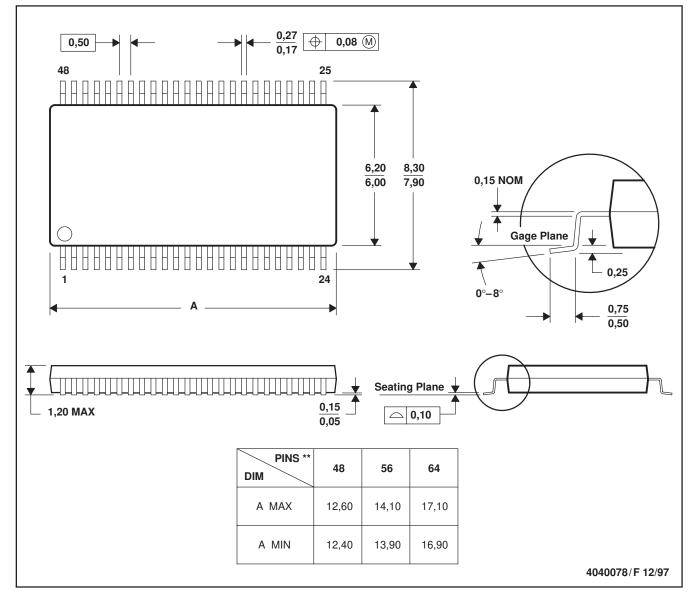
MECHANICAL DATA

MTSS003D - JANUARY 1995 - REVISED JANUARY 1998

DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2022, Texas Instruments Incorporated